



Formation of PtSn₄ and PtSn in the initial reaction between Pt and molten Sn

Ting-Yu Liu^a, Kuang-Kuo Wang^{a,*}, Hui-Chun Huang^a, Yuang-Shing Fang^a, Cheng-Fong Yeh^a,
Yu-Wei Hsu^a, Derhsin Gan^a, Hsing-Lu Huang^b

^a Department of Materials and Optoelectronic Science, National Sun Yat-Sen University, Kaohsiung, Taiwan, ROC

^b Department of Mechanical Engineering, R.O.C. Military Academy, Kaohsiung, Taiwan, ROC

ARTICLE INFO

Keywords:

Platinum

Tin, reflow

Transmission electron microscope (TEM)

PtSn

PtSn₄

Nucleation

ABSTRACT

The initial reaction between Pt and molten Sn has been studied by dipping tests of 1 and 2 s. It was found that both PtSn and PtSn₄ formed in the first second of contact. PtSn formed 7 nm (1 s) and 20 nm (2 s) thick layers on top of the Pt substrate but PtSn₄ formed scattered particles in the liquid Sn. No orientation relationship was found between Pt and PtSn. PtSn nucleates heterogeneously on Pt by its larger energy of formation than PtSn₄ and PtSn₄ nucleates in liquid Sn by the very low solubility of Pt in molten Sn.

1. Introduction

Platinum is a noble metal and can be used as a base metal or metallization layer on integrated circuits because of its high oxidation resistance, low dissolution rates [1–4] and acceptable wetting properties [1] in molten solders. However, experimental studies of its reaction with Sn or Sn-containing solders are very limited. In reflow process, the intermetallic compound (IMC) PtSn₄ was observed to form first [1,2,5,6] and Pt₃Sn and Pt₂Sn₃ formed afterward with further exposure [1]. In solid/solid reaction only the formation of PtSn₄ was reported [4,7]. Clearly, the understandings of the sequence and the mechanisms of the formation of the Pt–Sn IMCs are far from complete. Further detailed research work is necessary for the application of Pt in micro-electronic industries.

The purpose of this research was to study the very early stage reaction between Pt and molten Sn. The IMCs formed and the possible orientation relationships at their interfaces were studied using transmission electron microscopy (TEM) and high-resolution TEM. The reactions were performed by dipping tests of very short time, only 1 and 2 s. The formation mechanisms of the observed IMCs at the Pt/Sn interface were discussed.

2. Experimental details

Pt foil (99.9% pure) 0.1 mm thick was cut into 15 mm × 5 mm rectangles and was fully annealed in vacuum at 1200 °C for 6 h to enlarge its grain size. The Pt foils were degreased with acetone and the cleaned by dipping in a 7 ml HCl + 1 ml HNO₃ + 8 ml H₂O solution for

several minutes. Then the Pt foils were then cleaned with acetone, methanol and deionized water and were immediately dipped into a molten Sn bath (99.97% pure) at 240 ± 1 °C for 1 or 2 s and followed by quenching in ice water. The specimen surfaces were studied with a scanning electron microscope (SEM, JEOL JSM–6330, 5–10 kV). X-ray diffraction (XRD, Simens D5000) was conducted by using a Cu target and scanned at a step rate of 0.04° per second. The Sn on the specimen surface was removed.

The layer of Sn and IMCs on the surface of the reacted specimen were first thinned by polishing with abrasive papers. The remaining Sn was then carefully partially removed by electrochemical reduction with K–50 solutions (Kokico., Tokyo, Japan). The partial removal of Sn was important because some IMC particles could be retained for observation by the small amount of Sn left on the surface. Otherwise only the IMCs directly attached to the Pt surface could be studied. TEM specimens were prepared by focused ion beam. Selected area diffraction (SAD), bright and dark field images, and high-resolution lattice-fringes images by TEM (Philips, CM200, operating at 200 kV) were used for analysis.

3. Results

Fig. 1 is the XRD pattern of the specimen surface dipped in liquid Sn for 2 s. Weak peaks of PtSn₄ were detected. A typical SEM micrograph of the specimen surfaces after dipping is shown in Fig. 2. The surface is already densely covered with IMCs and the larger ones are plate-like. These are PtSn₄, as has been reported in the literature [1,2,5,6], and was confirmed by X-ray diffraction (results not shown) and the following TEM analyses. The characteristic plate-like morphology was

* Corresponding author.

E-mail address: kk_wang@mail.nsysu.edu.tw (K.-K. Wang).

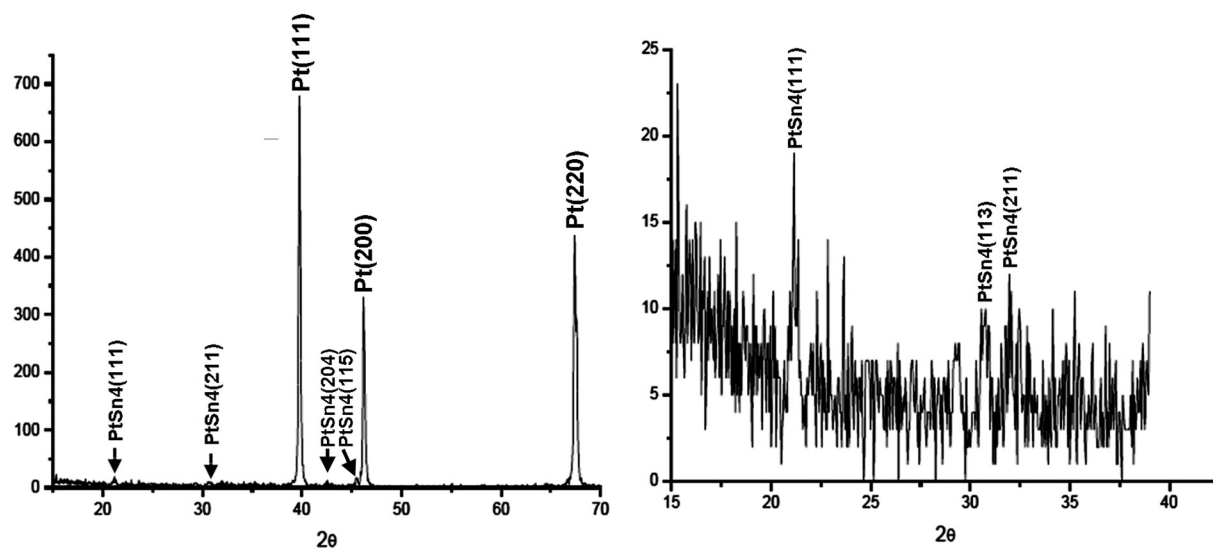


Fig. 1. XRD pattern of the specimen surface dipped in liquid Sn for 2 s.

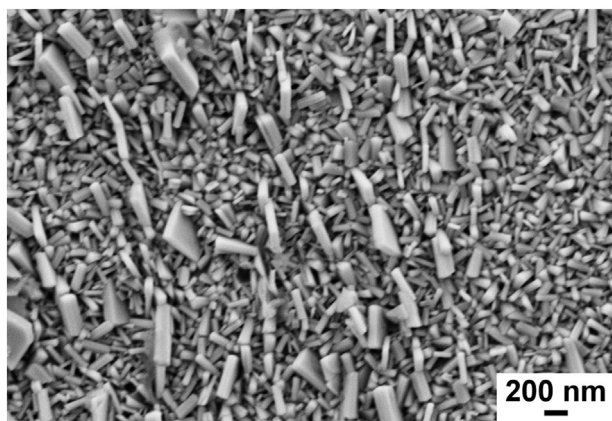


Fig. 2. SEM micrograph of the specimen surface dipped in liquid Sn for 2 s.

analyzed and the plate surface was shown to be the (001) plane [8].

Fig. 3 shows the cross-sectional view of the specimen dipped for 1 s. Above the interface, marked as C, many IMC particles were successfully retained by Sn. TEM SAD pattern confirmed that these particles are

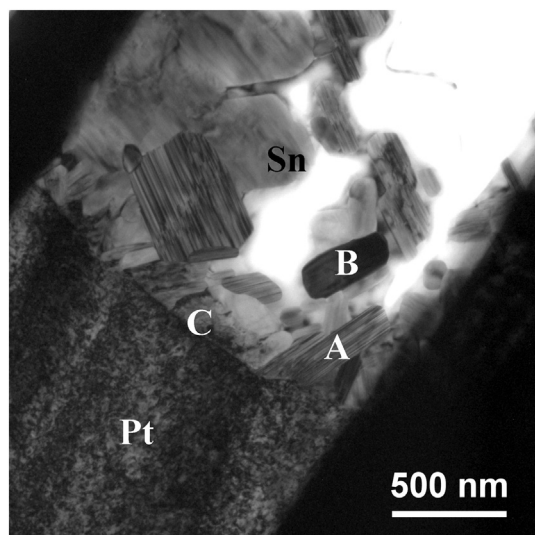


Fig. 3. Cross-sectional view of the Pt interface of the specimen dipped for 1 s.

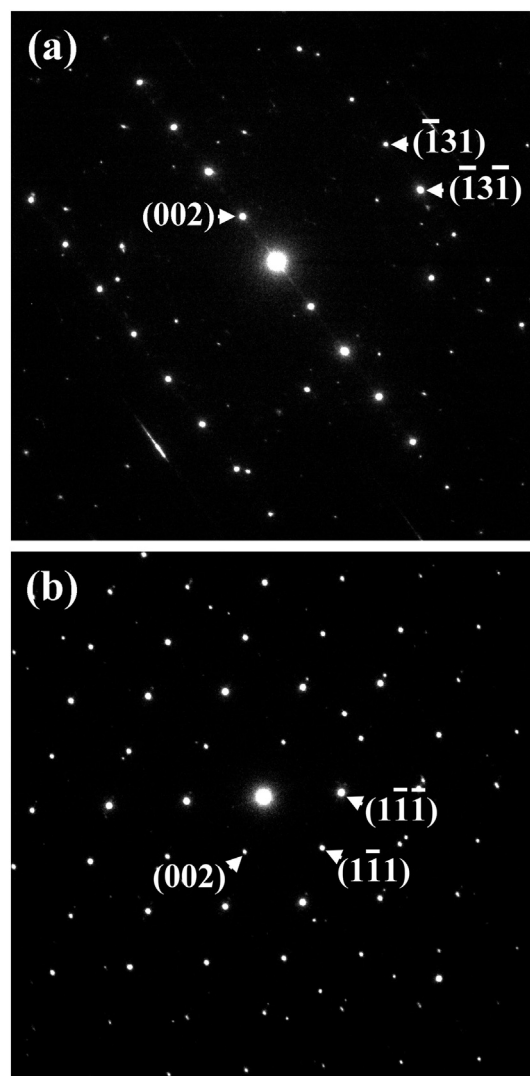


Fig. 4. (a) TEM SAD pattern of particle A in Fig. 3, showing it is PtSn₄ in the [310] zone. (b) The same of particle B in the [110] zone.

Download English Version:

<https://daneshyari.com/en/article/8032529>

Download Persian Version:

<https://daneshyari.com/article/8032529>

[Daneshyari.com](https://daneshyari.com)